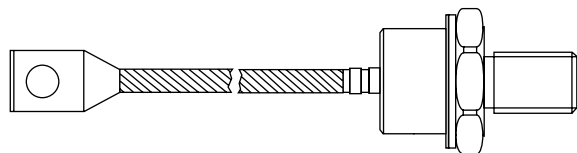


Standard Recovery Diodes (Stud Version), 400 A



DO-205AB (DO-9)

FEATURES

- Wide current range
- High surge current capabilities
- Stud cathode and stud anode version
- Standard JEDEC types
- RoHS compliant
- Designed and qualified for industrial level



TYPICAL APPLICATIONS

- Converters
- Power supplies
- Machine tool controls
- High power drives

PRODUCT SUMMARY

$I_{F(AV)}$	400 A
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MAJOR RATINGS AND CHARACTERISTICS

PARAMETER	TEST CONDITIONS	VALUES	UNITS
$I_{F(AV)}$		400	A
	T_C	120	°C
$I_{F(RMS)}$		630	A
I_{FSM}	50 Hz	8250	A
	60 Hz	8640	
I^2t	50 Hz	340	kA ² s
	60 Hz	311	
V_{RRM}	Range	800 to 1600	V
T_J		- 40 to 200	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA
400U(R)	80	800	900	15
	120	1200	1300	
	160	1600	1700	

400U(R) Series

Vishay High Power Products Standard Recovery Diodes (Stud Version), 400 A

FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature	$I_{F(AV)}$	180° conduction, half sine wave		400	A
				120	°C
Maximum RMS forward current	$I_{F(RMS)}$	DC at 110 °C case temperature		630	A
Maximum peak, one cycle forward, non-repetitive surge current	I_{FSM}	t = 10 ms	No voltage reappplied	8250	A
		t = 8.3 ms		8640	
		t = 10 ms	100 % V_{RRM} reappplied	6940	
		t = 8.3 ms		7270	
Maximum I^2t for fusing	I^2t	t = 10 ms	No voltage reappplied	340	kA ² s
		t = 8.3 ms		311	
		t = 10 ms	100 % V_{RRM} reappplied	241	
		t = 8.3 ms		220	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	t = 0.1 to 10 ms, no voltage reappplied		3400	kA ² √s
Low level value of threshold voltage	$V_{F(TO)1}$	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.77	V
High level value of threshold voltage	$V_{F(TO)2}$	(I > $\pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.85	
Low level value of forward slope resistance	r_{f1}	(16.7 % $\times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.49	mΩ
High level value of forward slope resistance	r_{f2}	(I > $\pi \times I_{F(AV)}$), $T_J = T_J$ maximum		0.49	
Maximum forward voltage drop	V_{FM}	$I_{pk} = 1500$ A, $T_J = T_J$ maximum, $t_p = 10$ ms sinusoidal wave		1.62	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum junction operating and storage temperature range	T_J, T_{Stg}			- 40 to 200	°C
Maximum thermal resistance, junction to case	R_{thJC}	DC operation		0.15	K/W
Maximum thermal resistance, case to heatsink	R_{thCS}	Mounting surface, smooth, flat and greased		0.04	
Maximum allowed mounting torque ± 10 %		Not lubricated threads		27	N · m
Approximate weight				250	g
Case style		See dimensions - link at the end of datasheet		DO-205AB (DO-9)	

ΔR_{thJC} CONDUCTION				
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.020	0.013	$T_J = T_J$ maximum	K/W
120°	0.023	0.023		
90°	0.029	0.031		
60°	0.042	0.044		
30°	0.073	0.074		

Note

- The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

400U(R) Series

Standard Recovery Diodes Vishay High Power Products (Stud Version), 400 A

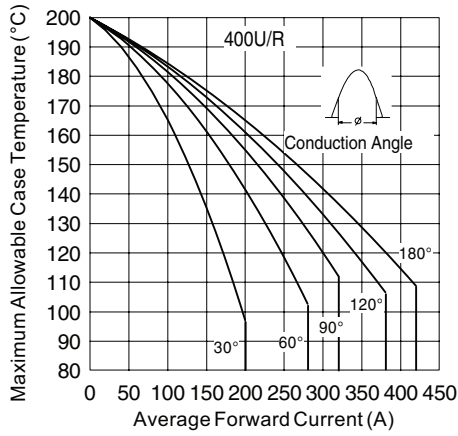


Fig. 1 - Current Ratings Characteristics

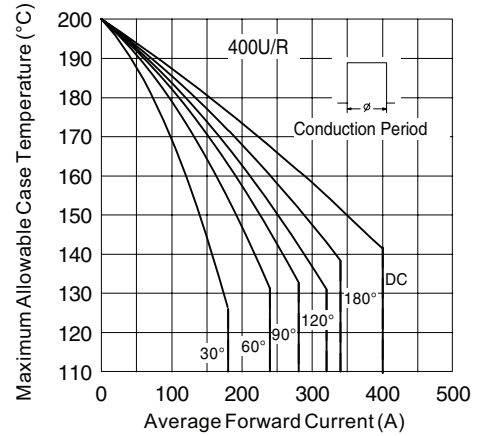


Fig. 2 - Current Ratings Characteristics

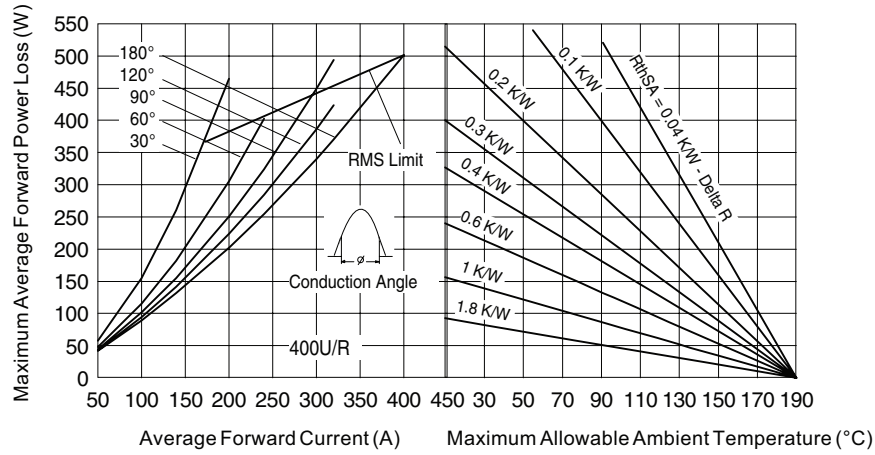


Fig. 3 - Forward Power Loss Characteristics

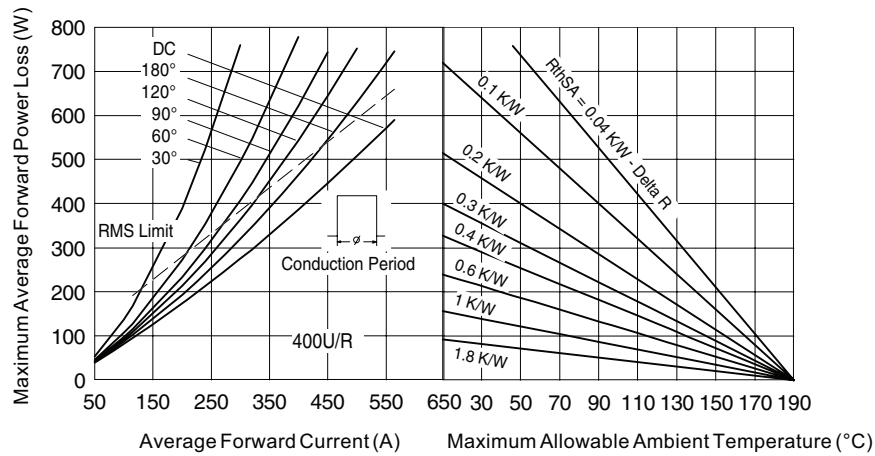


Fig. 4 - Forward Power Loss Characteristics

400U(R) Series

Vishay High Power Products Standard Recovery Diodes (Stud Version), 400 A

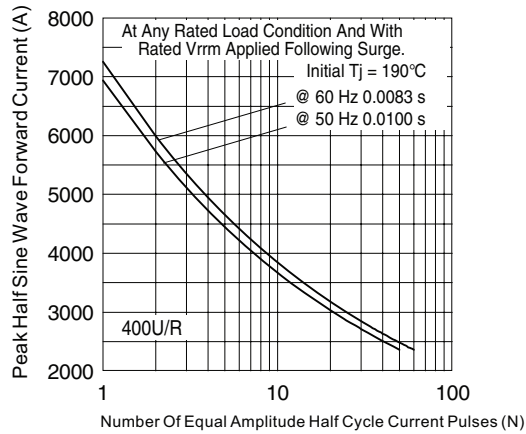


Fig. 5 - Maximum Non-Repetitive Surge Current

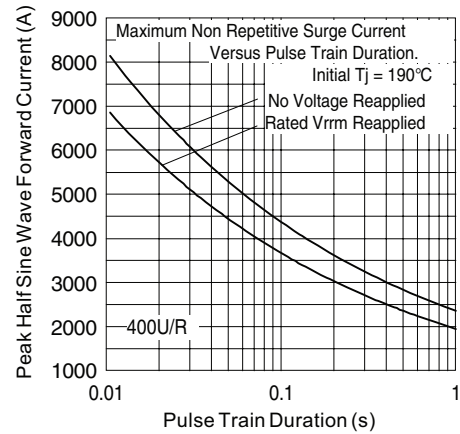


Fig. 6 - Maximum Non-Repetitive Surge Current

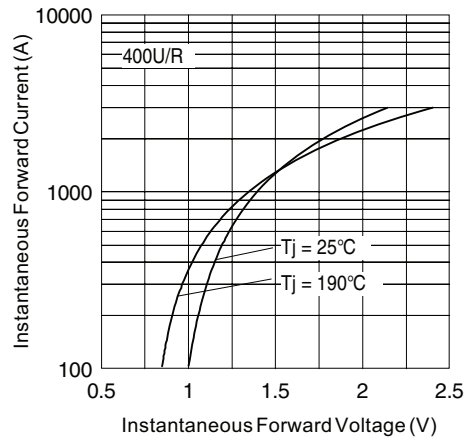


Fig. 7 - Forward Voltage Drop Characteristics

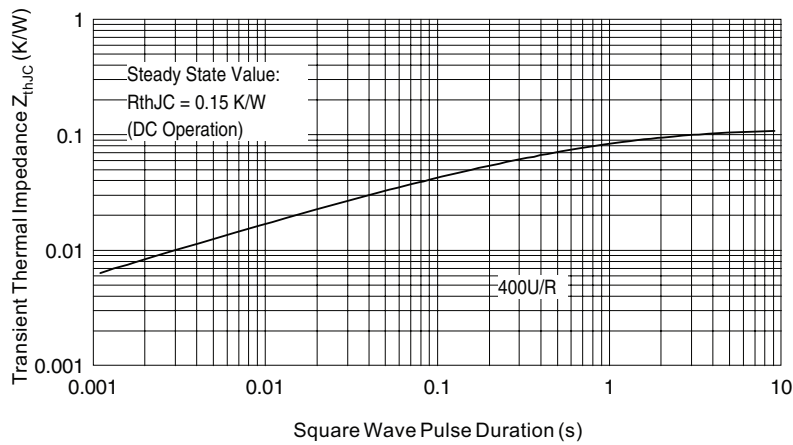
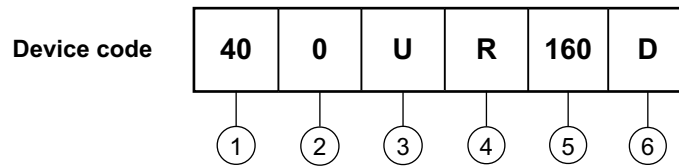


Fig. 8 - Thermal Impedance Z_{thJC} Characteristic

ORDERING INFORMATION TABLE



- 1** - 40 = Essential part number
- 2** - 0 = Standard recovery device
- 3** - U = Stud normal polarity (cathode to stud)
- 4** -
 - None = Stud normal polarity (cathode to stud)
 - R = Stud reverse polarity (anode to stud)
- 5** - Voltage code x 10 = V_{RRM} (see Voltage Ratings table)
- 6** - Diffused diode

Note: For metric device M16 x 1.5 contact factory

LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95339

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